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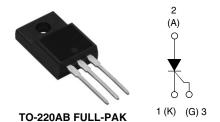






Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 16 A



PRODUCT SUMMARY			
V _T at 10 A 1.4 V			
I _{TSM}	200 A		
V _{RRM}	800/1200 V		

DESCRIPTION/FEATURES

The 16TTS..FP High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

Fully isolated package (V_{INS} = 2500 V_{RMS}) is UL E78996 approved

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	13.5	17	А	

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	METER TEST CONDITIONS VALUES		UNITS	
I _{T(AV)}	Sinusoidal waveform 10		А	
I _{RMS}		16	^	
V _{DRM} /V _{RRM}		800/1200	V	
I _{TSM}		200	A	
V _T	10 A, T _J = 25 °C	1.4	V	
dV/dt		500	V/µs	
dl/dt		150	A/μs	
T _J	Range	- 40 to 125	°C	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
16TTS08FP	800	10			
16TTS12FP	1200	1200	10		

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEGT COMPITIONS		ES UNITS
PARAMETER	STINIBUL	TEST CONDITIONS	TYP.	MAX.
Maximum average on-state current	I _{T(AV)}	T _c = 95 °C, 180° conduction, half sine wave	10	
Maximum RMS on-state current	I _{RMS}		16	Α .
Maximum peak, one-cycle,	1	10 ms sine pulse, rated V _{RRM} applied	170	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	200	
Marriago um 124 fau fracia a	l ² t	10 ms sine pulse, rated V _{RRM} applied	144	A ² s
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied	200	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	2000) A ² √s
Maximum on-state voltage drop	V_{TM}	10 A, T _J = 25 °C	1.4	V
On-state slope resistance	r _t	T 405 00	24.0	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C	1.1	V
Mariana	1 /1	T _J = 25 °C	0.5	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	$T_J = 25 \degree C$ $V_R = Rated V_{RRM}/V_{DRM}$	10	
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A 16TTS08FP, 16TTS12FP	-	100 mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load	200	
Maximum rate of rise of off-state voltage	dV/dt		500	V/µs
Maximum rate of rise of turned-on current	dI/dt		150	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	w
Maximum average gate power	P _{G(AV)}		2.0]
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	90	mA
		Anode supply = 6 V, resistive load, T _J = 25 °C	60	
		Anode supply = 6 V, resistive load, T _J = 125 °C	35	
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	3.0	
		Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	v
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0]
Maximum DC gate voltage not to trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}, V_{\text{DRM}} = \text{Rated value}$ 0.2 2.0		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	4	μs
Typical turn-off time	tq	1 1 1 2 5 6	110	



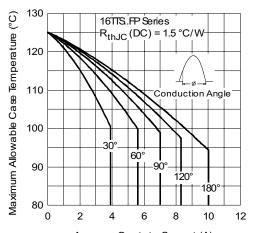
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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J , T_{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	1.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque ———	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Madina davias			Coop at the TO 200AB FULL BAK (04A/0)	16TTS08FP	
Marking device			Case style TO-220AB FULL-PAK (94/V0)	16TTS12FP	

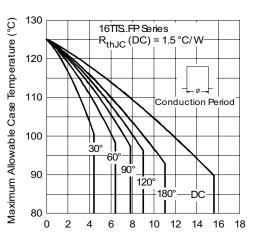
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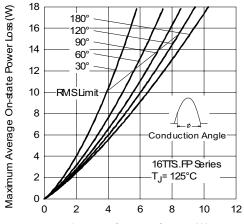




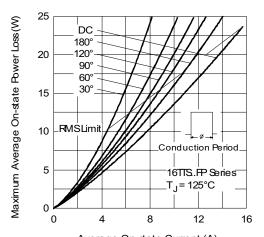
Average On-state Current (A) Fig. 1 - Current Rating Characteristics



Average On-state Current (A)
Fig. 2 - Current Rating Characteristics



Average On-state Current (A)
Fig. 3 - On-State Power Loss Characteristics



Average On-state Current (A) Fig. 4 - On-State Power Loss Characteristics

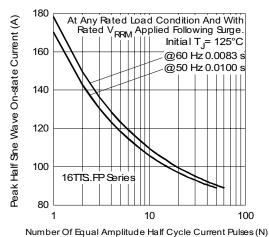


Fig. 5 - Maximum Non-Repetitive Surge Current

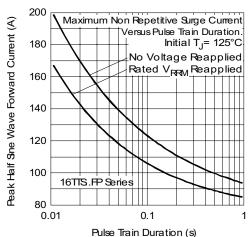


Fig. 6 - Maximum Non-Repetitive Surge Current



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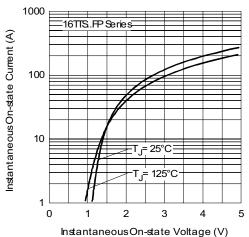


Fig. 7 - On-State Voltage Drop Characteristics

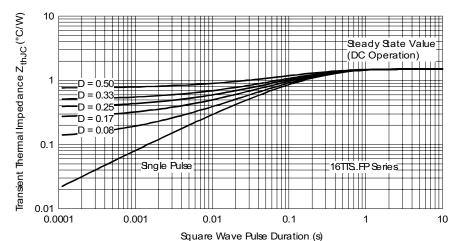
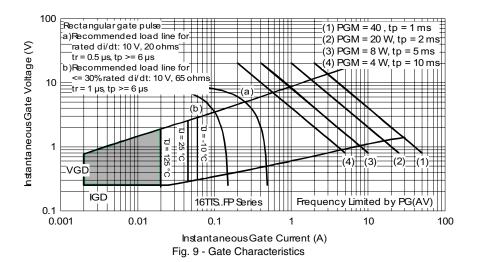


Fig. 8 - Thermal impedance Z_{thJC} Characteristics



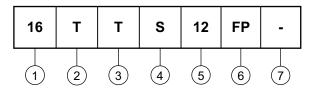
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ORDERING INFORMATION TABLE

Device code



1 - Current rating, RMS value

2 - Circuit configuration:

T = Single thyristor

- Package:

T = TO-220AB

4 - Type of silicon:

S = Converter grade

- Voltage code x 100 = V_{RRM} -

08 = 800 V 12 = 1200 V

6 - FULL-PAK

7 - • None = Standard production

• PbF = Lead (Pb)-free

Note: For higher voltage up to 1600 V contact factory

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95072			
Part marking information	http://www.vishay.com/doc?95069		



Vishay

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